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### Features

- Maximum Junction Temperature : T<sub>J</sub> = 175°C
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- + Low Saturation Voltage:  $V_{CE(sat)}$  = 1.9 V(Typ.) @ I<sub>C</sub> = 40 A
- Fast Switching : E<sub>OFF</sub> = 6.5 uJ/A
- Tighten Parameter Distribution
- RoHS Compliant

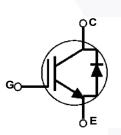
## Applications

- Solar Inverter, UPS, Welder, PFC, Induction Heating
- Telecom, ESS

# **General Description**

Using novel field stop IGBT technology, Fairchild's new series of field stop 2<sup>nd</sup> generation IGBTs offer the optimum performance for solar inverter, UPS, welder, induction heating, telecom, ESS and PFC applications where low conduction and switching losses are essential.





# **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		650	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
* GES	Transient Gate to Emitter Voltage		± 30	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	80	A
·U	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	40	A
I <sub>CM (1)</sub>	Pulsed Collector Current		120	A
le .	Diode Forward Current	@ T <sub>C</sub> = 25°C	40	A
$I_{F}$ Diode Forward Current $@ T_{C} = 100$	@ T <sub>C</sub> = 100 <sup>o</sup> C	20	А	
I <sub>FM (1)</sub>	Pulsed Diode Maximum Forward Currer	nt	120	A
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	349	W
· D	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	174	W
TJ	Operating Junction Temperature		-55 to +175	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	i	300	°C

### Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

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# **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	1.5	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

# Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA40N65SMD	FGA40N65SMD	TO-3PN	Tube	N/A	N/A	30

# Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	$V_{GE}$ = 0 V, I <sub>C</sub> = 250 $\mu$ A	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA	-	0.6	-	V/ºC
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE}$ = $V_{GES}$ , $V_{CE}$ = 0 V	-	-	±400	nA
On Charac	teristics					
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 250 μA, V <sub>CE</sub> = V <sub>GE</sub>	3.5	4.5	6.0	V
		I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	-	1.9	2.5	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 175^{\circ}\text{C}$	-	2.1	-	V
Dynamic C	Characteristics					
C <sub>ies</sub>	Input Capacitance		-	1880	-	pF
C <sub>oes</sub>	Output Capacitance	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V, f = 1 MHz	-	180	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance		-	50	-	pF
Switching	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time		- T	12	16	ns
t <sub>r</sub>	Rise Time		-	20	28	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 40 A,	-	92	120	ns
t <sub>f</sub>	Fall Time	$R_G = 6 \Omega$ , $V_{GE} = 15 V$ ,	-	13	17	ns
E <sub>on</sub>	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 25°C	-	0.82	1.23	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.26	0.34	mJ
E <sub>ts</sub>	Total Switching Loss		-	1.08	1.57	mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	15	- \	ns
t <sub>r</sub>	Rise Time		-	22	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 40 A,	-	116	-	ns
t <sub>f</sub>	Fall Time	R <sub>G</sub> = 6 Ω, V <sub>GE</sub> = 15 V,	-	16	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 175 <sup>o</sup> C	-	1.08	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss	]	-	0.60	-	mJ
E <sub>ts</sub>	Total Switching Loss	]	-	1.68	-	mJ

# Electrical Characteristics of the IGBT (Continued)

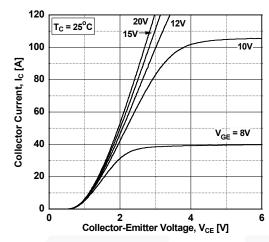
Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	119	180	nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	-	13	20	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	58	90	nC

# Electrical Characteristics of the Diode T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Condi	tions	Min.	Тур.	Max	Unit
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25°C	-	2.1	2.6	V
* FM	blode i orward voltage	1 <sub>F</sub> 2077	T <sub>C</sub> = 175°C	-	1.7	-	v
E <sub>rec</sub>	Reverse Recovery Energy		T <sub>C</sub> = 175 <sup>o</sup> C	-	96	-	uJ
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> =20 A,	T <sub>C</sub> = 25°C	-	42	-	ns
٩r			T <sub>C</sub> = 175°C	-	200	-	
I	Diode Peak Reverse Recovery Current		T <sub>C</sub> = 25 <sup>o</sup> C	-	3.6	-	А
'm			T <sub>C</sub> = 175°C	-	8.0	-	
Q <sub>rr</sub> Dio	Diode Reverse Recovery Charge		T <sub>C</sub> = 25°C	-	76	-	nC
≪ll			T <sub>C</sub> = 175 <sup>o</sup> C	-	800	-	

# Typical Performance Characteristics

### Figure 1. Typical Output Characteristics





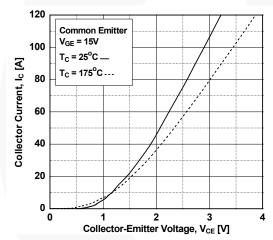


Figure 5. Saturation Voltage vs. V<sub>GE</sub>

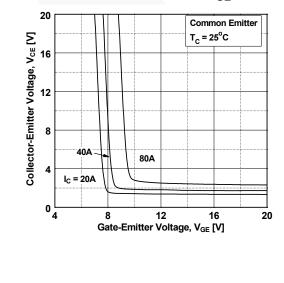
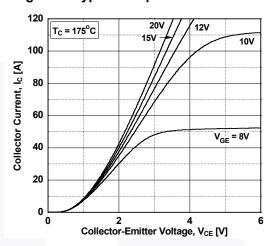
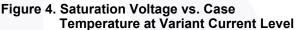
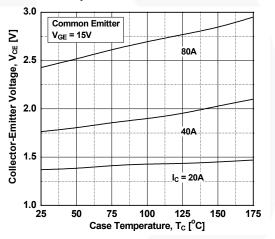
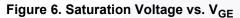


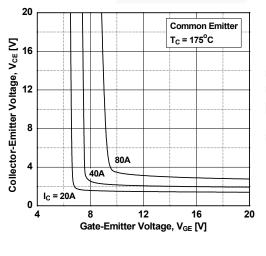
Figure 2. Typical Output Characteristics

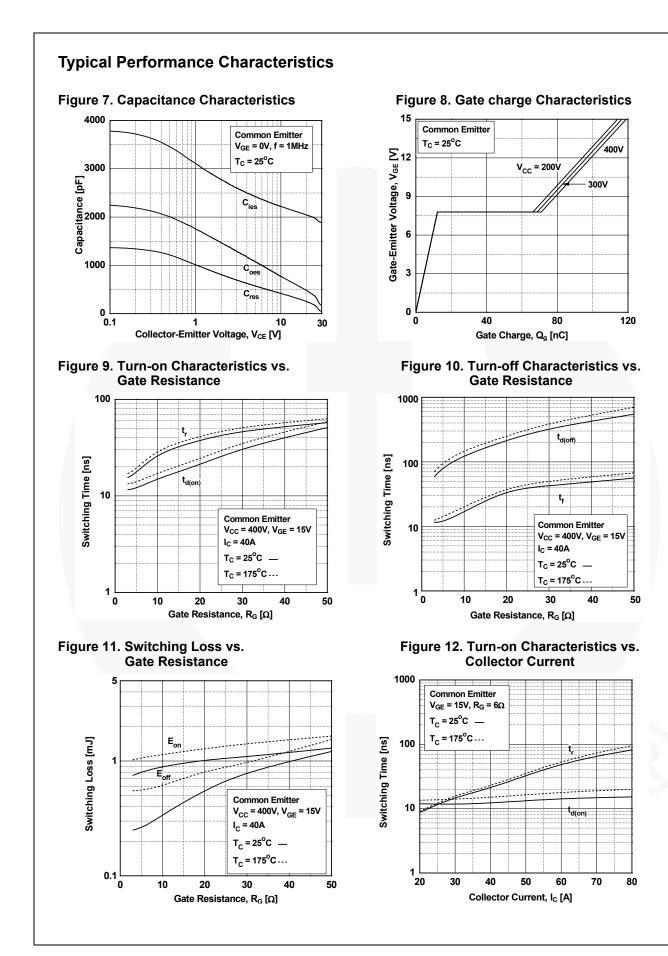




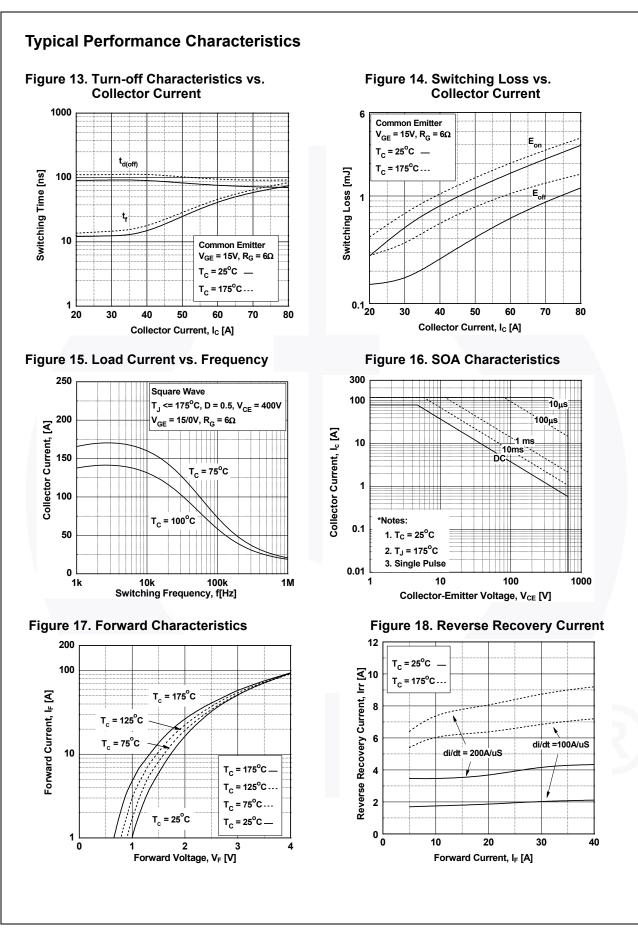


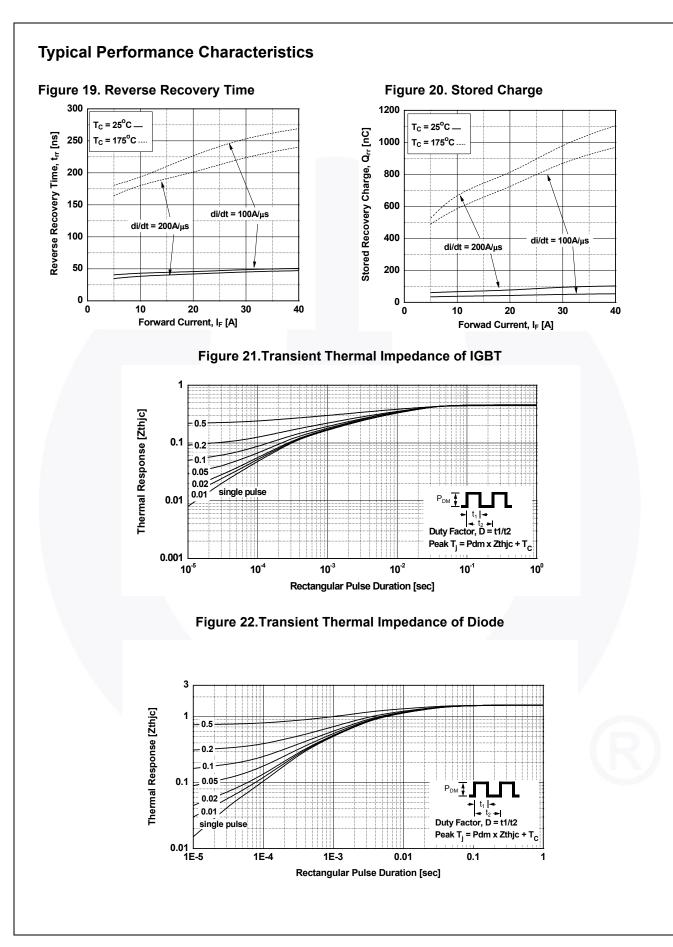


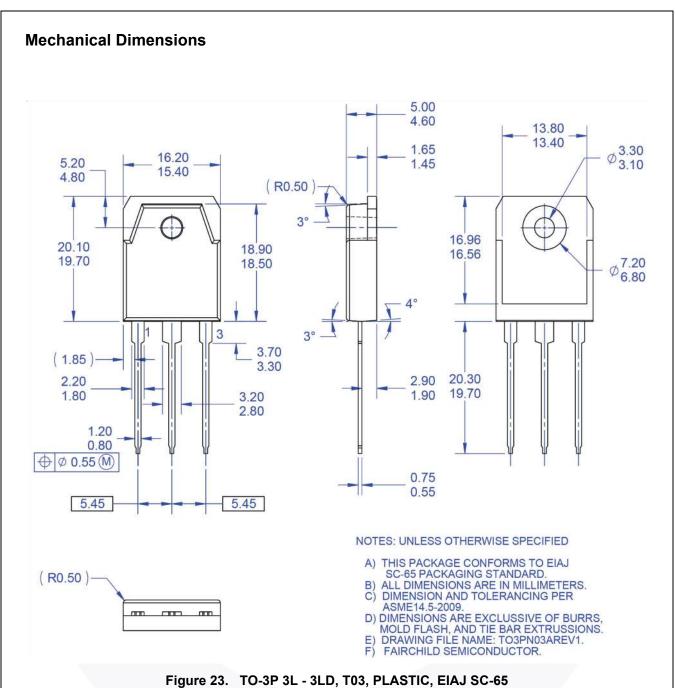




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